



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## N-Channel Power MOSFET

30V, 52A, 8.5mΩ

### FEATURES

- Low  $R_{DS(on)}$  to minimize conductive Losses
- Low gate charge for fast power switching
- 100% UIS and  $R_g$  tested
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

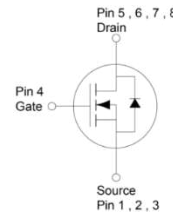
### APPLICATIONS

- DC-DC Converters
- Battery Power Management
- ORing FET/Load Switch

PRODUCT SUMMARY			
PARAMETER		VALUE	UNIT
$V_{DS}$		30	V
$R_{DS(on)}$ (max)	$V_{GS} = 10V$	8.5	mΩ
	$V_{GS} = 4.5V$	13	
$Q_g$		7.2	nC



PDFN33



**Notes:** MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		$V_{DS}$	30	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Continuous Drain Current (Note 1)	$T_C = 25^\circ\text{C}$	$I_D$	52	A
	$T_A = 25^\circ\text{C}$		13	
Pulsed Drain Current (Note 1)		$I_{DM}$	208	A
Single Pulse Avalanche Current (Note 2)		$I_{AS}$	23	A
Single Pulse Avalanche Energy (Note 2)		$E_{AS}$	26	mJ
Total Power Dissipation	$T_C = 25^\circ\text{C}$	$P_D$	37	W
	$T_C = 125^\circ\text{C}$		7	
Total Power Dissipation	$T_A = 25^\circ\text{C}$	$P_D$	2.3	W
	$T_A = 125^\circ\text{C}$		0.5	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	- 55 to +150	$^\circ\text{C}$

THERMAL RESISTANCE			
PARAMETER	SYMBOL	LIMIT	UNIT
Thermal Resistance – Junction to Case	$R_{\theta JC}$	3.4	$^\circ\text{C/W}$
Thermal Resistance – Junction to Ambient	$R_{\theta JA}$	53	$^\circ\text{C/W}$

**Thermal Performance Note:**  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins.  $R_{\theta JA}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.

ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	BV <sub>DSS</sub>	30	--	--	V
Gate Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250μA	V <sub>GS(TH)</sub>	1	1.6	2.5	V
Gate-Source Leakage Current	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V	I <sub>GSS</sub>	--	--	±100	nA
Drain-Source Leakage Current	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 30V	I <sub>DSS</sub>	--	--	1	μA
Drain-Source On-State Resistance (Note 3)	V <sub>GS</sub> = 10V, I <sub>D</sub> = 13A	R <sub>DS(on)</sub>	--	6.2	8.5	mΩ
	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 13A		--	9	13	
Forward Transconductance (Note 3)	V <sub>DS</sub> = 5V, I <sub>D</sub> = 13A	g <sub>fs</sub>	--	27	--	S
Dynamic (Note 4)						
Total Gate Charge	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 15V, I <sub>D</sub> = 13A	Q <sub>g</sub>	--	14.3	--	nC
Total Gate Charge	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 15V, I <sub>D</sub> = 13A	Q <sub>g</sub>		7.2		
Gate-Source Charge		Q <sub>gs</sub>	--	2.6	--	
Gate-Drain Charge		Q <sub>gd</sub>	--	3.4	--	
Input Capacitance	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 15V, f = 1.0MHz	C <sub>iss</sub>	--	817	--	pF
Output Capacitance		C <sub>oss</sub>	--	155	--	
Reverse Transfer Capacitance		C <sub>rss</sub>	--	96	--	
Gate Resistance	f = 1.0MHz, open drain	R <sub>g</sub>	0.8	2.8	5.6	Ω
Switching (Note 4)						
Turn-On Delay Time	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 15V, I <sub>D</sub> = 15A, R <sub>G</sub> = 3.3Ω,	t <sub>d(on)</sub>	--	4.8	--	ns
Rise Time		t <sub>r</sub>	--	12.5	--	
Turn-Off Delay Time		t <sub>d(off)</sub>	--	27.6	--	
Fall Time		t <sub>f</sub>	--	8.2	--	
Source-Drain Diode						
Diode Forward Voltage (Note 3)	V <sub>GS</sub> = 0V, I <sub>S</sub> = 13A	V <sub>SD</sub>	--	--	1	V
Reverse Recovery Time	I <sub>S</sub> = 13A, di/dt = 100A/μs	t <sub>rr</sub>	--	13	--	ns
Reverse Recovery Charge		Q <sub>rr</sub>	--	6.3	--	nC

**Notes:**

- Current limited by package.
- $L = 0.1mH, V_{GS} = 10V, V_{DS} = 25V, R_G = 25\Omega, I_{AS} = 23A$ , Starting  $T_J = 25^\circ\text{C}$
- Pulse test: Pulse Width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .
- Switching time is essentially independent of operating temperature.

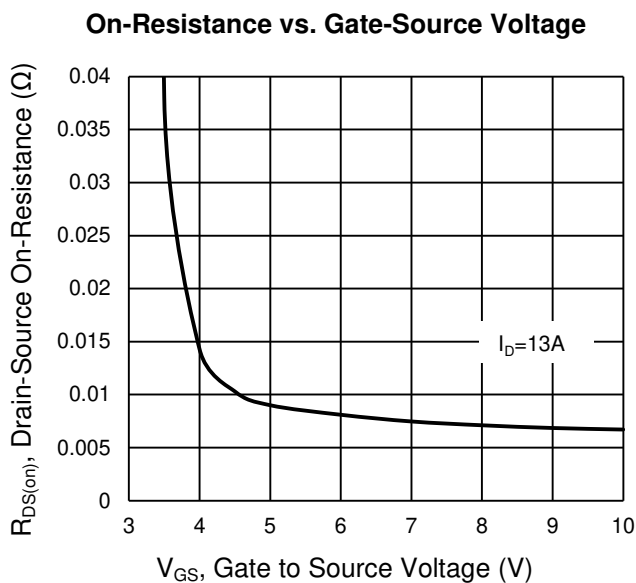
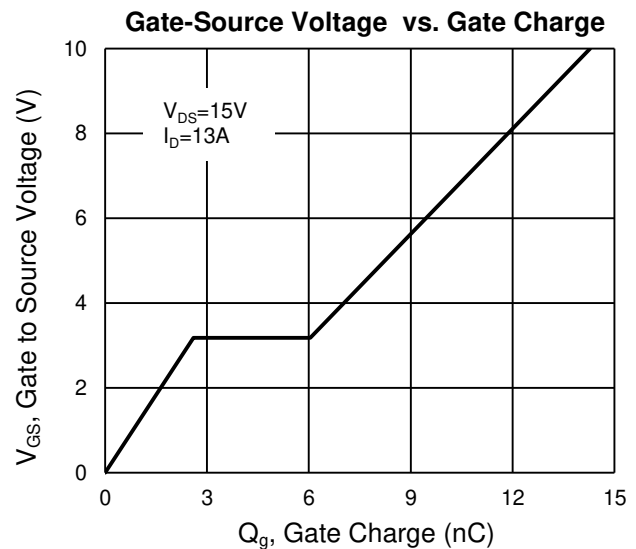
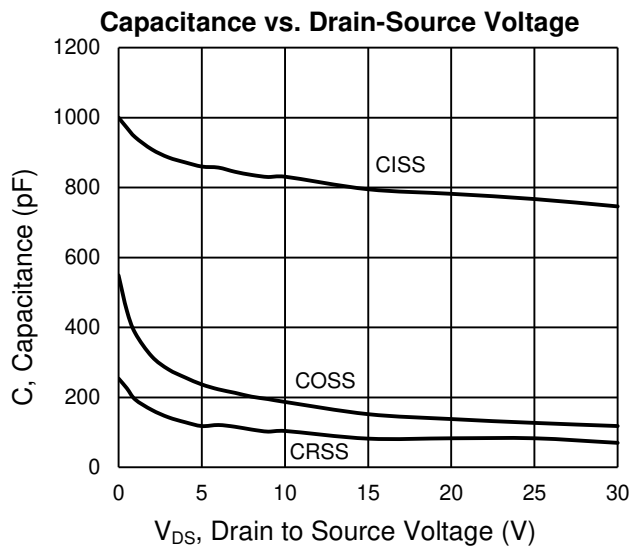
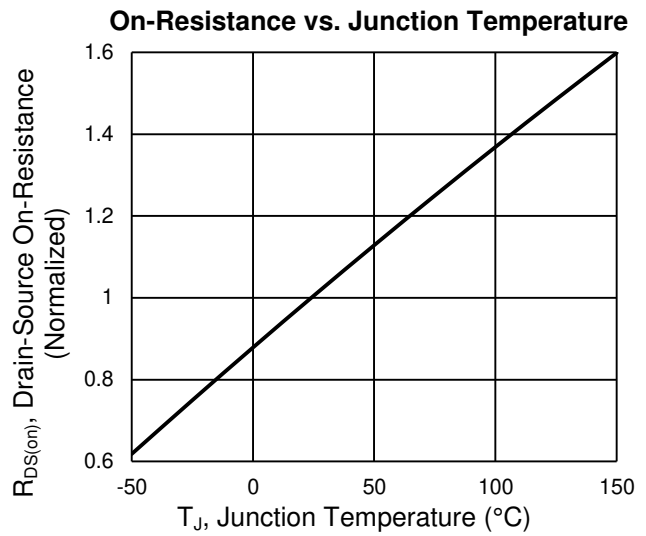
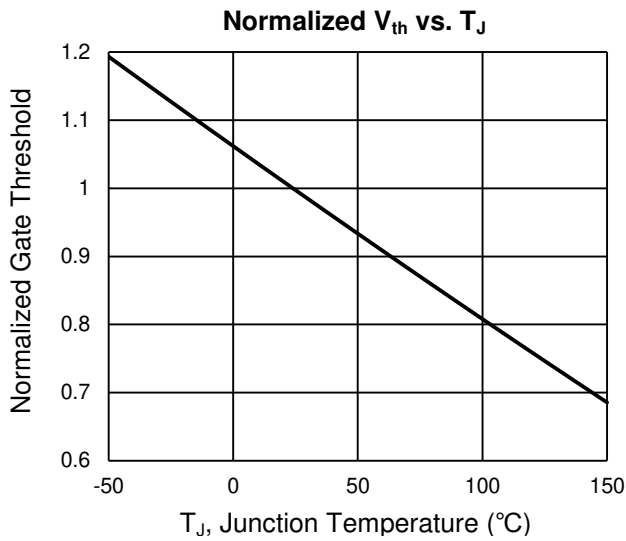
**ORDERING INFORMATION**

PART NO.	PACKAGE	PACKING
TSM085N03PQ33 RGG	PDFN33	5,000pcs / 13" Reel

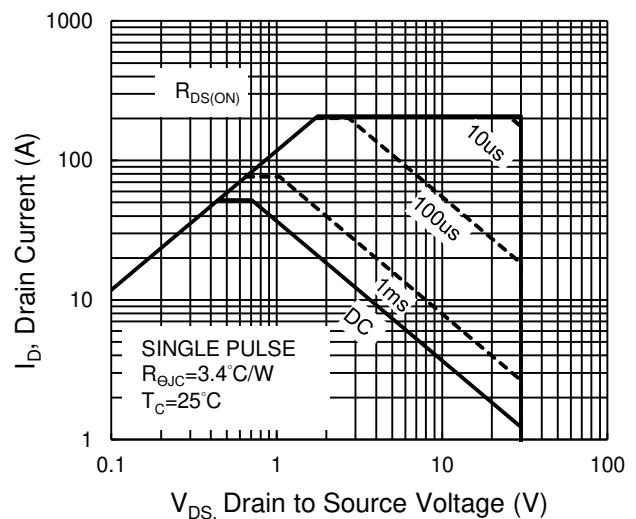


## CHARACTERISTICS CURVES

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

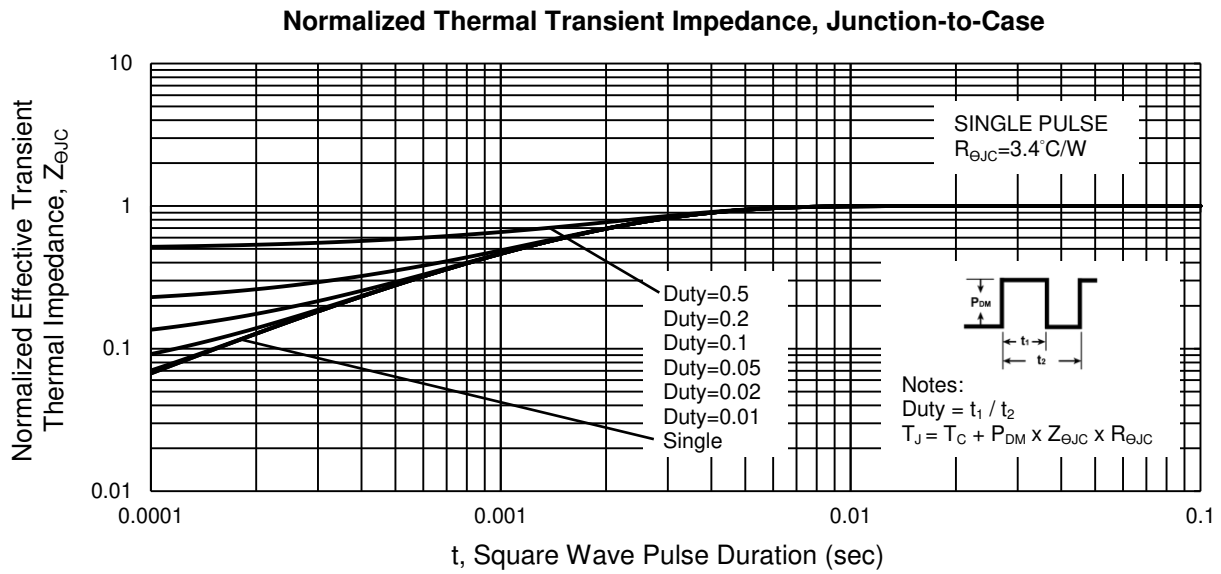


## Maximum Safe Operating Area, Junction-to-Case



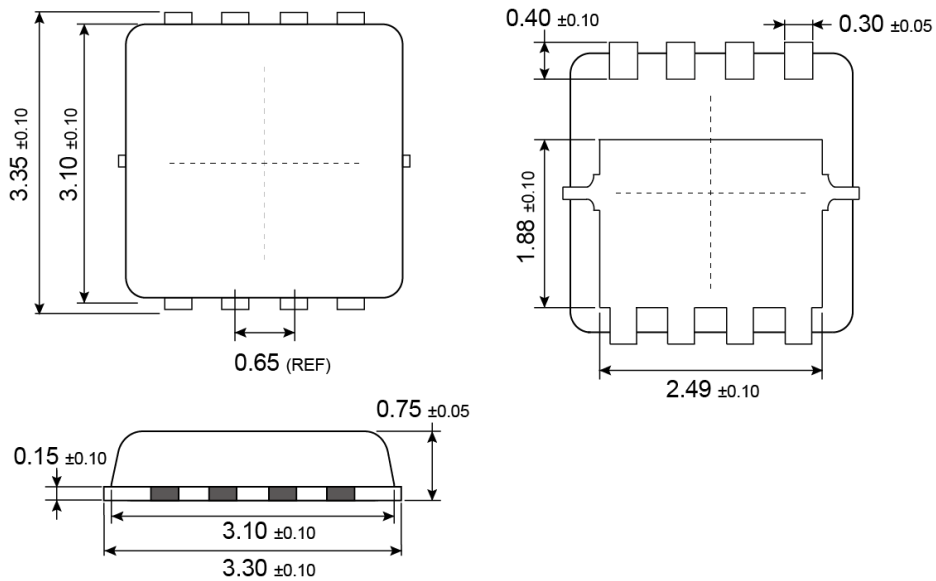
## CHARACTERISTICS CURVES

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

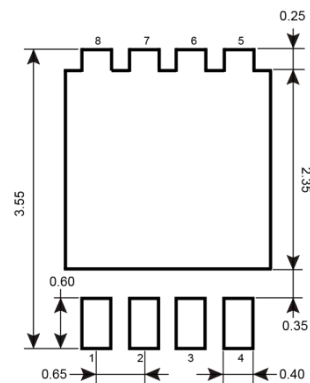


**PACKAGE OUTLINE DIMENSIONS** (Unit: Millimeters)

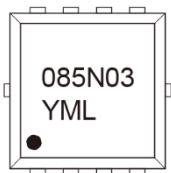
**PDFN33**



**SUGGESTED PAD LAYOUT** (Unit: Millimeters)



**MARKING DIAGRAM**



**Y** = Year Code  
**M** = Month Code for Halogen Free Product  
**O** =Jan **P** =Feb **Q** =Mar **R** =Apr  
**S** =May **T** =Jun **U** =Jul **V** =Aug  
**W** =Sep **X** =Oct **Y** =Nov **Z** =Dec  
**L** = Lot Code (1~9, A~Z)

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